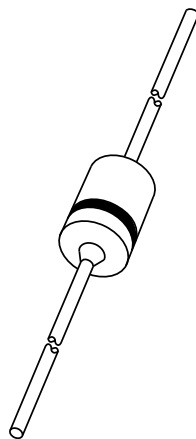


# DATA SHEET



## **1N4148; 1N4446; 1N4448** High-speed diodes

Product specification  
Supersedes data of April 1992  
File under Discrete Semiconductors, SC01

1996 Apr 15

## High-speed diodes

## 1N4148; 1N4446; 1N4448

## FEATURES

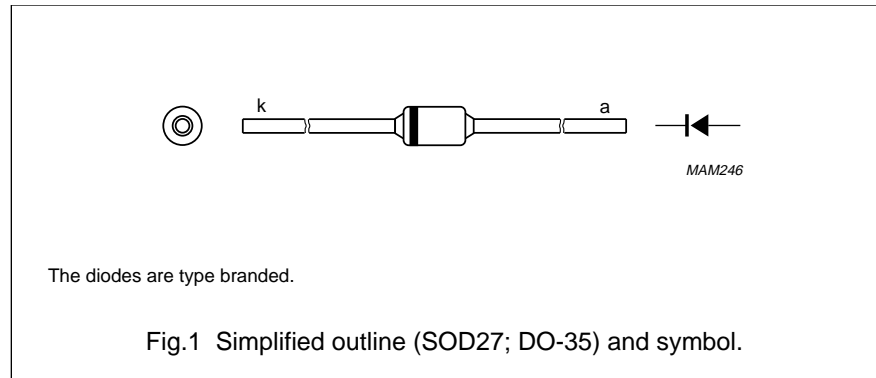
- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- General application
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 450 mA
- Forward voltage: max. 1 V.

## APPLICATIONS

- High-speed switching.

## DESCRIPTION

The 1N4148, 1N4446, 1N4448 are high-speed switching diodes fabricated in planar technology, and encapsulated in hermetically sealed leaded glass SOD27 (DO-35) packages.



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	75	V
$V_R$	continuous reverse voltage		–	75	V
$I_F$	continuous forward current	see Fig.2; note 1	–	200	mA
$I_{FRM}$	repetitive peak forward current		–	450	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 1\ \text{ms}$ $t = 1\ \text{s}$	–	4 1 0.5	A A A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	200	°C

## Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

## High-speed diodes

## 1N4148; 1N4446; 1N4448

**ELECTRICAL CHARACTERISTICS**

$T_j = 25\text{ °C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	see Fig.3			
	1N4148	$I_F = 10\text{ mA}$	–	1.0	V
	1N4446	$I_F = 20\text{ mA}$	–	1.0	V
	1N4448	$I_F = 5\text{ mA}$ $I_F = 100\text{ mA}$	0.62 –	0.72 1.0	V V
$I_R$	reverse current	$V_R = 20\text{ V}$ ; see Fig.5		25	nA
		$V_R = 20\text{ V}$ ; $T_j = 150\text{ °C}$ ; see Fig.5	–	50	$\mu\text{A}$
$I_R$	reverse current; 1N4448	$V_R = 20\text{ V}$ ; $T_j = 100\text{ °C}$ ; see Fig.5	–	3	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 0$ ; see Fig.6		4	pF
$t_{rr}$	reverse recovery time	when switched from $I_F = 10\text{ mA}$ to $I_R = 60\text{ mA}$ ; $R_L = 100\ \Omega$ ; measured at $I_R = 1\text{ mA}$ ; see Fig.7		4	ns
$V_{fr}$	forward recovery voltage	when switched from $I_F = 50\text{ mA}$ ; $t_r = 20\text{ ns}$ ; see Fig.8	–	2.5	V

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	350	K/W

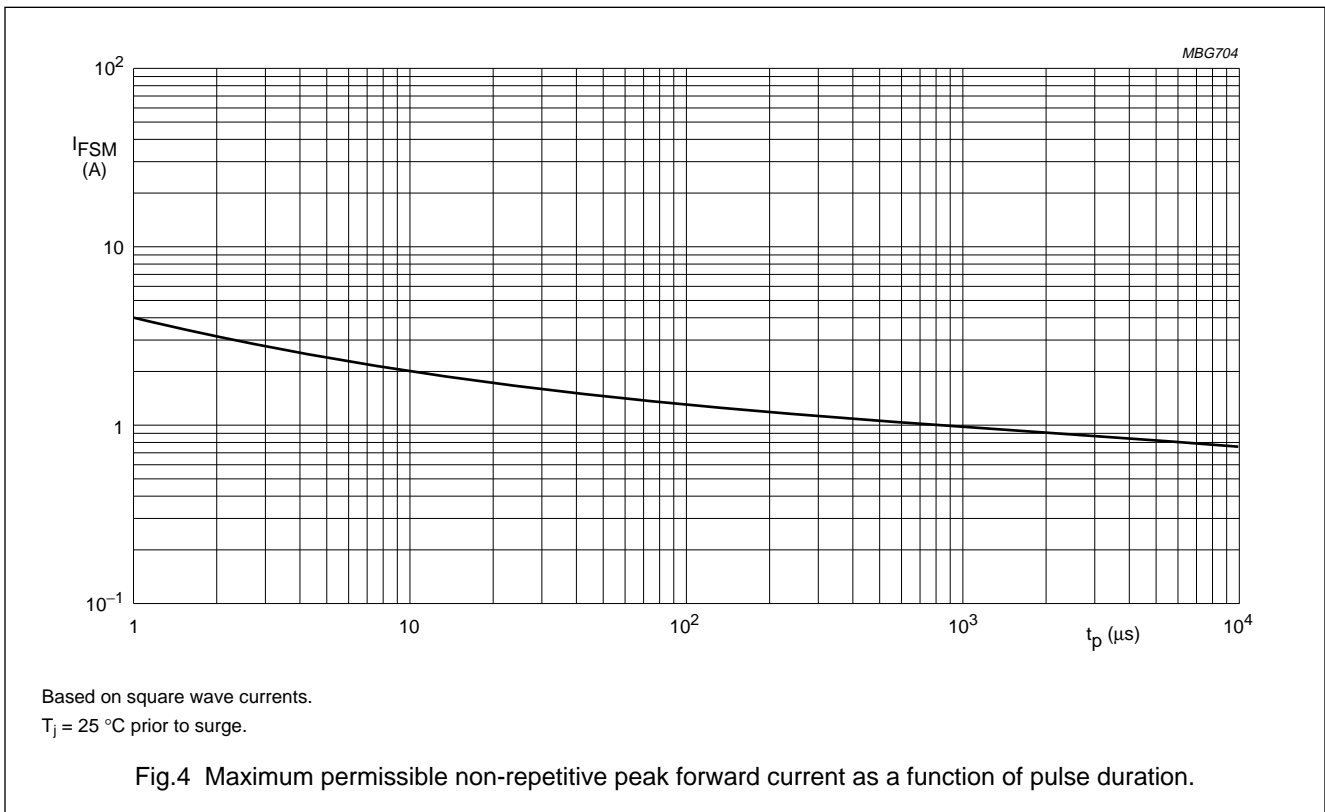
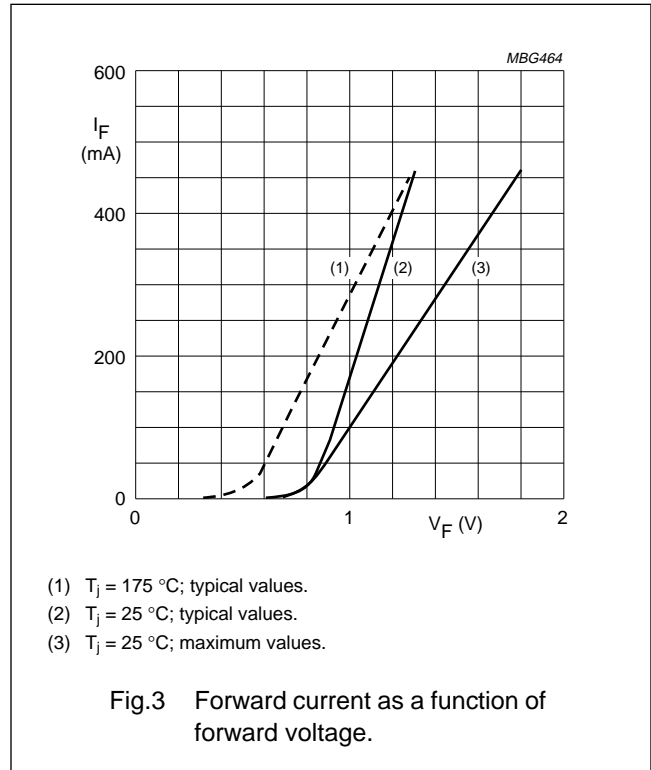
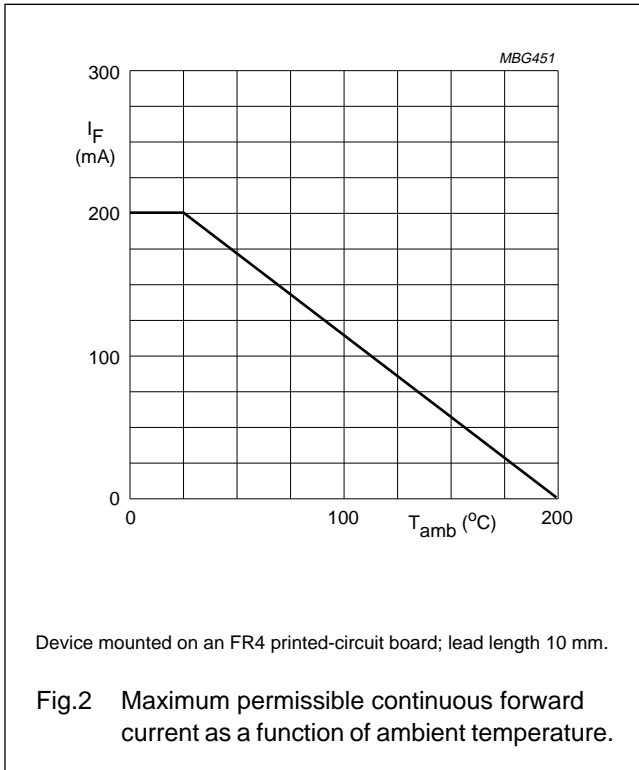
**Note**

1. Device mounted on a printed circuit-board without metallization pad.

High-speed diodes

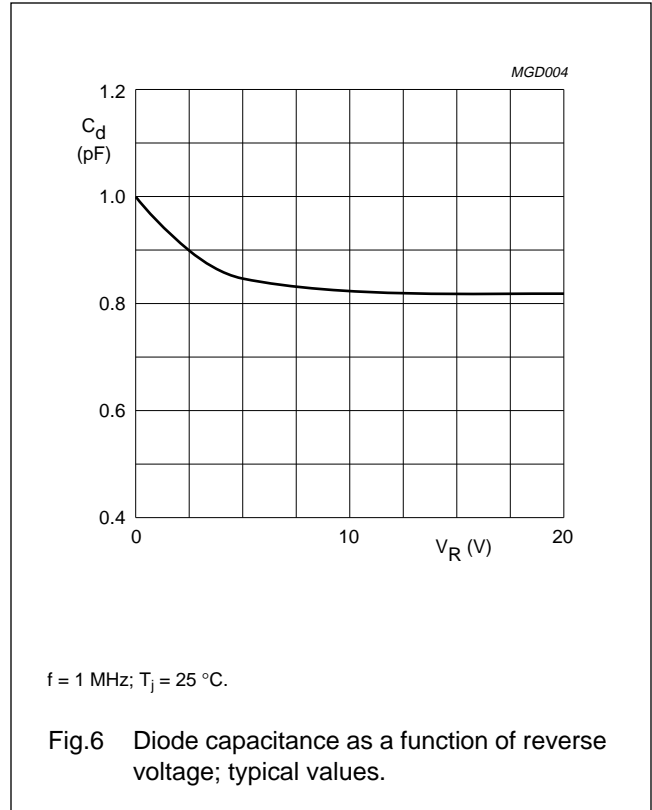
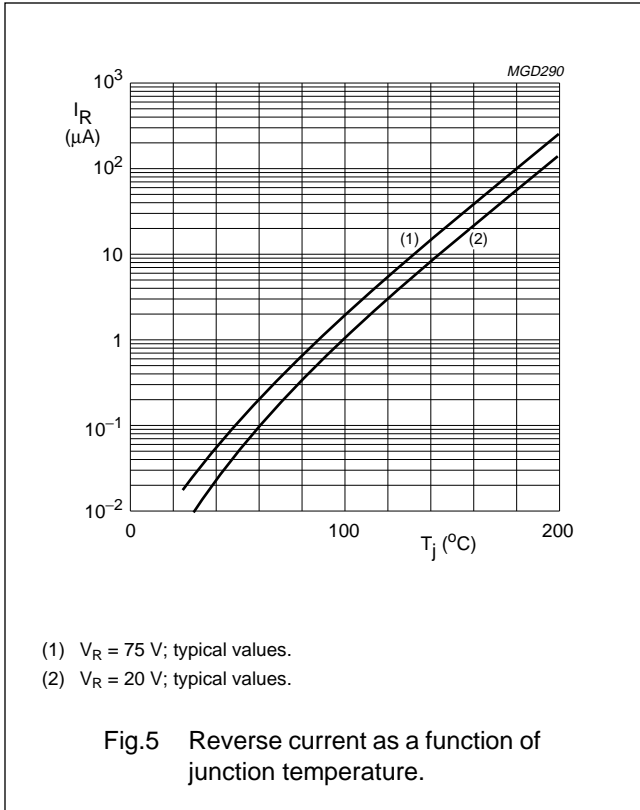
1N4148; 1N4446; 1N4448

GRAPHICAL DATA



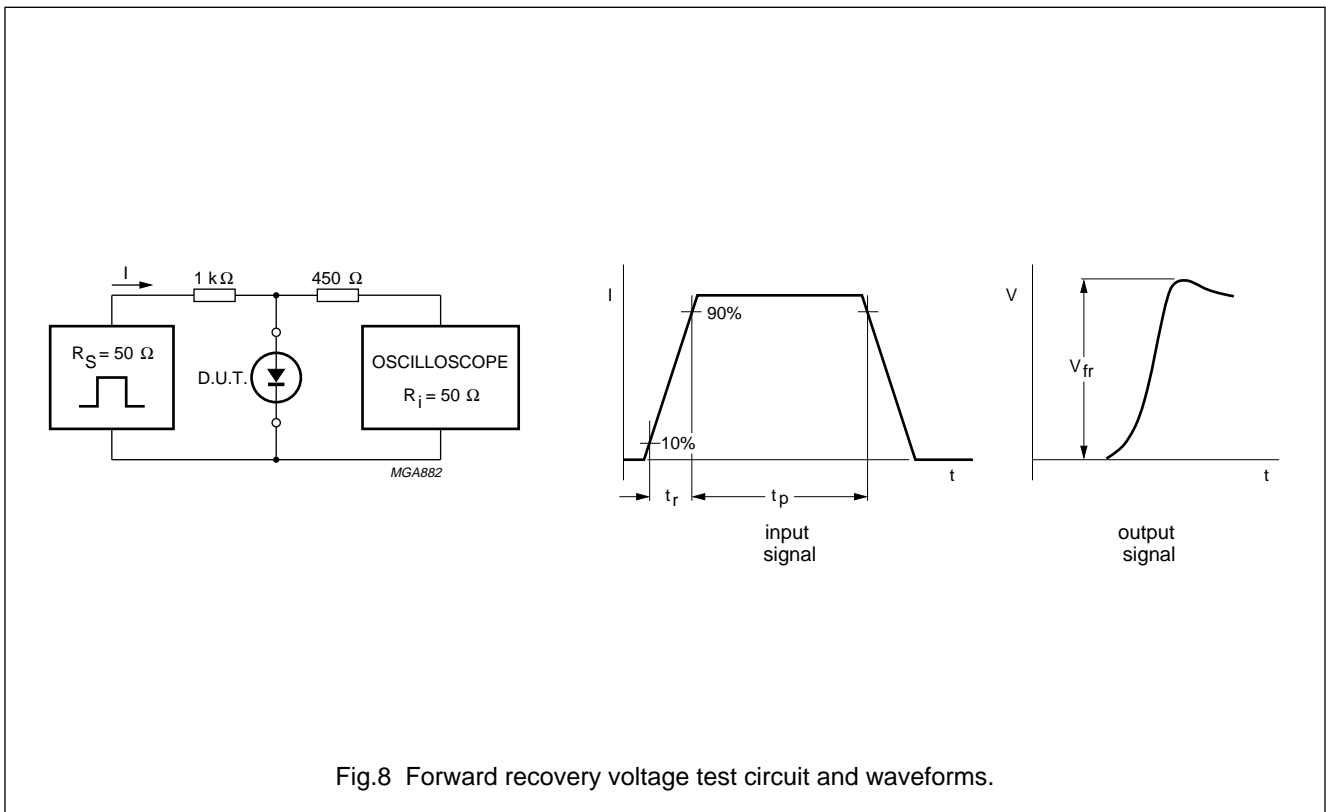
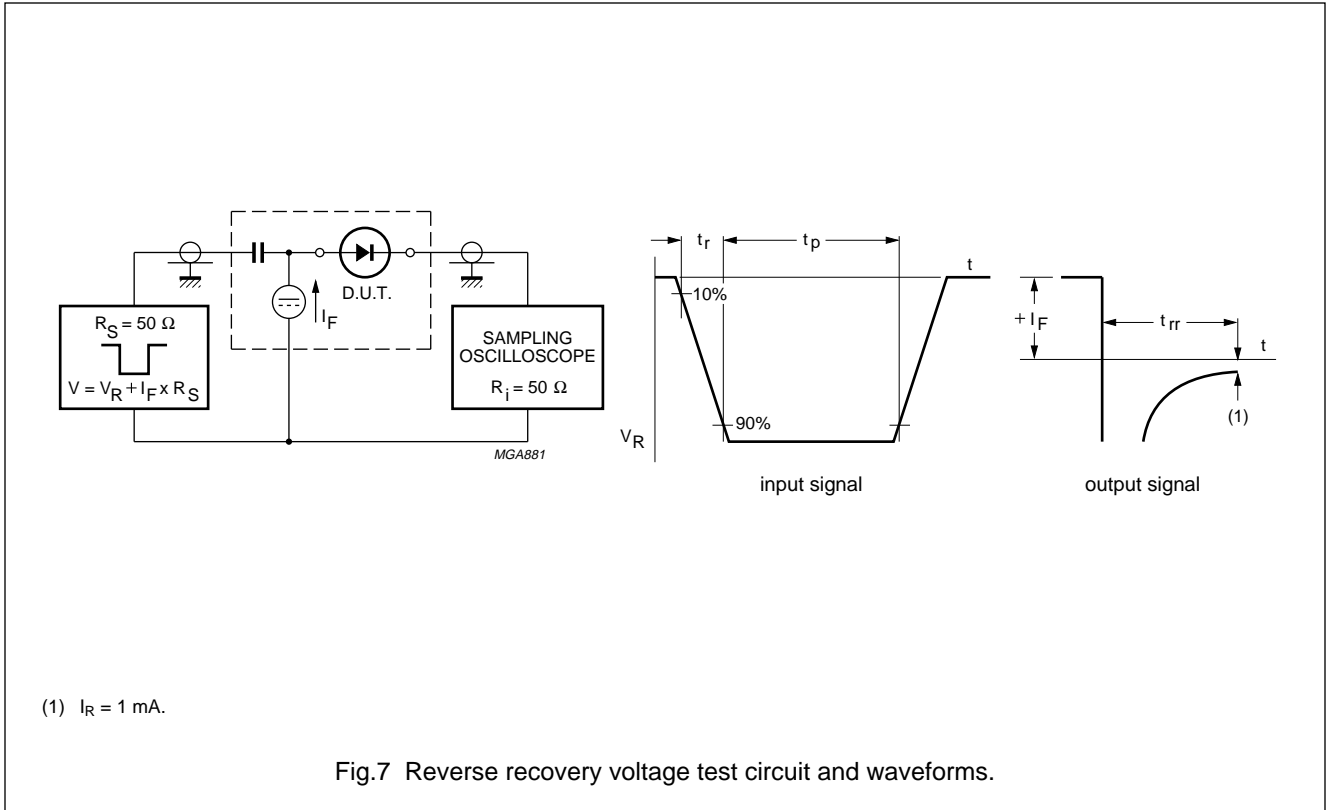
High-speed diodes

1N4148; 1N4446; 1N4448



High-speed diodes

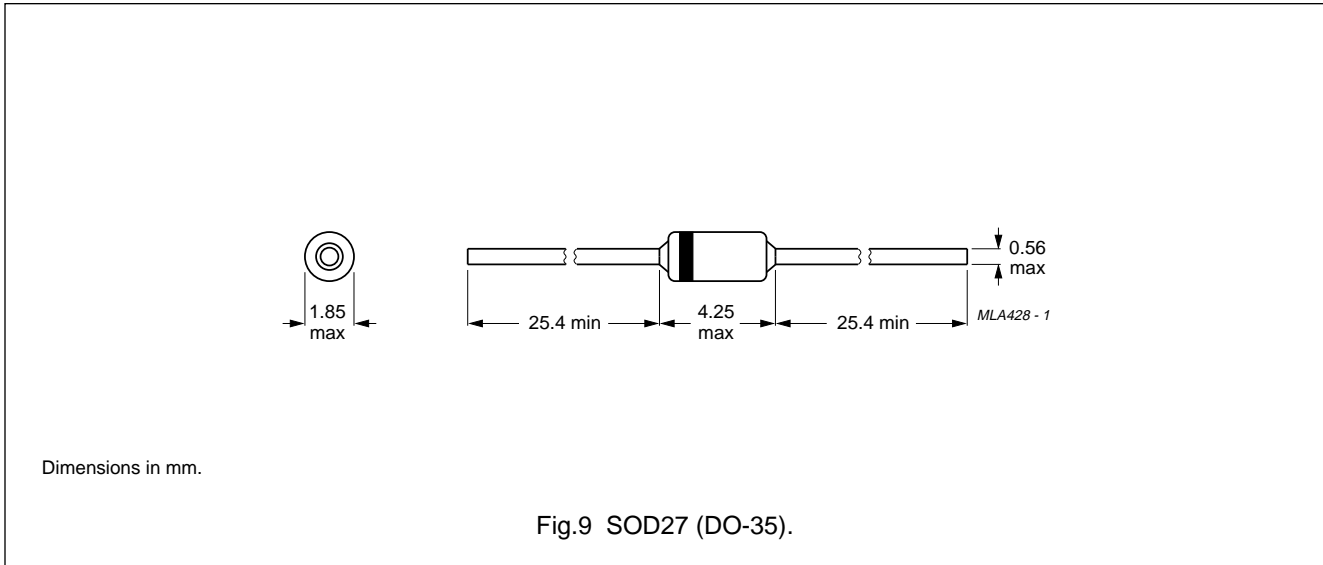
1N4148; 1N4446; 1N4448



# High-speed diodes

1N4148; 1N4446; 1N4448

## PACKAGE OUTLINE



## DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

## LIFE SUPPORT APPLICATIONS

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